Thin film Pb/Nb photocathodes

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Aim, motivation and Eucard 2 obligations,

D12.8

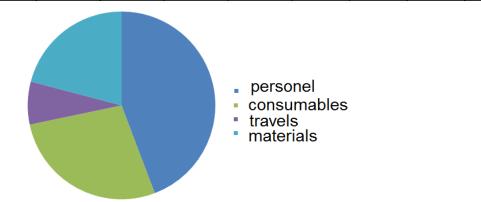
- MS 80 Demonstrated operation of improved deposition system, Pb layers of 1 μ m in thickness
- D12.8 Optimised procedure for microdorplets flattening with an UV laser

Reason

We found that plasma pulsed irradiation is more effective that the laser one. For plasma we learned how thick layer must be deposited to undergo a right change caused by energy deposition.

Optimised procedure for preparation of flat, clean and adherent Pb/Nb films

Benefic iary	Person* month	Personel cost per	Personel direct	Personel indirect	Consumab les	Travel direct	Materials and	Total direct	Total indirect	Total direc	EC contribut
		month					travels			+indir	ion
NCBJ	36	1927	69,389	41.634	69,000	18,500	52,500	156.889	94.134	251.023	98.134

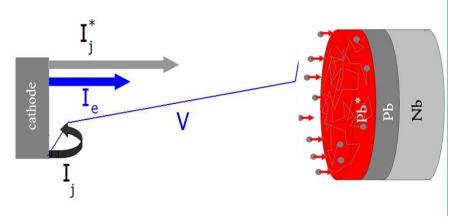






Cathodic arc

Explosive electron and Pb ions emission, ions accelerated in the pressure gradient and coupled to the electron flux



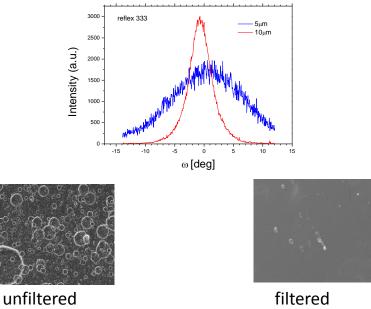
Growth

- Shallow inplantation
- diffusion with kinetic energy higher than displacement energy
- permanent ion exeed
- gradual cooling and condensation

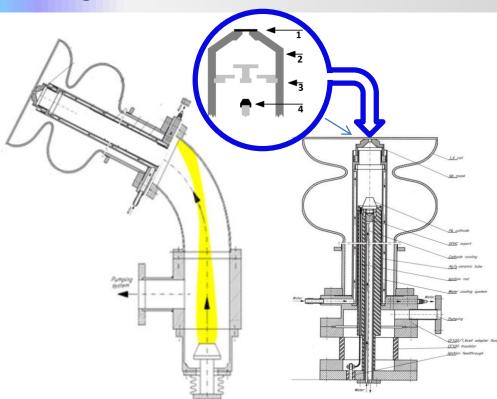
Consequences for the film:

EUCARD²

- regular
- dense
- adherent
- texture (111)
- micro-droplets



Filtering



Knee-like magnetic filter, deposition directly onto cavity back wall

Short distance – short time

Low througput long time, debrees

still debrees

Detachable plug, treatment of which is separated from the e-gun cavity. Performance has been tested vs the plasm channel length

INSULATOR

PUMPING

Pb CATHODI

ARGET POS.3

TARGET POS.2

TARGET POS.1

COIL

COIL

EUCARD²

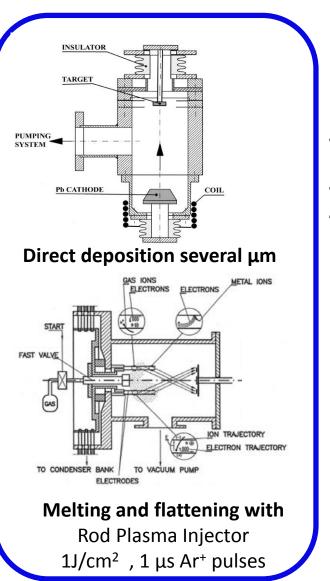


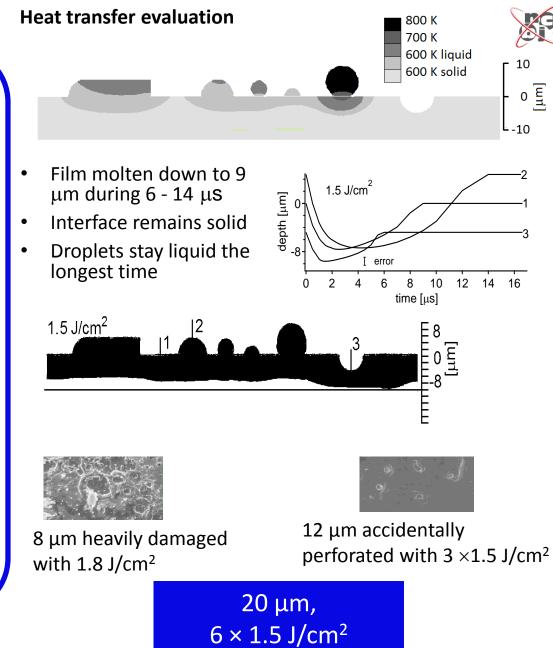
No trade off between droplets removal efficency and surface cleanliness has been found

Unfiltered deposition followed with a separatated flattening

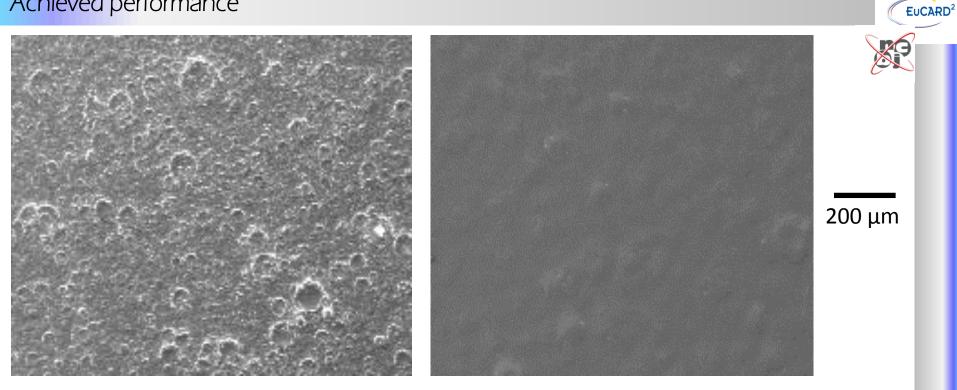
Deposition and flattening







Achieved performance

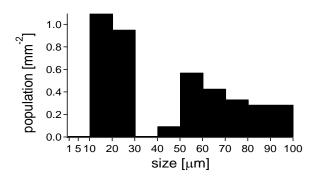


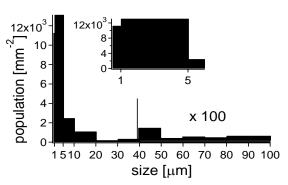
Applied treatment resulted in a continuous and uniform layer.

population	3 ⁻¹ 0 ⁴ mm ⁻¹	¹ 5 mm ⁻¹
droplets coverage	0.85	0.01
altitude difference	50 µm	1 μm (5 μm)
lateral correlation length	1 µm	100 µm

20 µm, $6 \times 1.5 \text{ J/cm}^2$

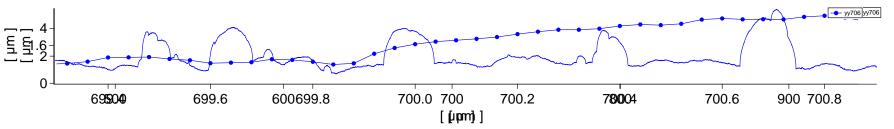
Surface models





EUCARD²

- $0.4 \times 4 \text{ mm}^2$ model areas were populated with droplets ensembles of radii distributions found with SEM inspection for as deposited and flattened samples, respectively
- Centres locations of hemispherical extrusions have been randomly chosen on the model areas in the grids of 40 nm resolving mesh
- Surface cross sectons profiles along randomly chosen 4 mm long streight lines have been calculated



- Distributions of fragments normals inclination angles to the overall surface normal has been calculated
- Electric field was calculated in the surface vicinity by applying a voltage beteween that surface and the plane in the infinity, which corresonds to 40 MV/m at the ideally flat surface

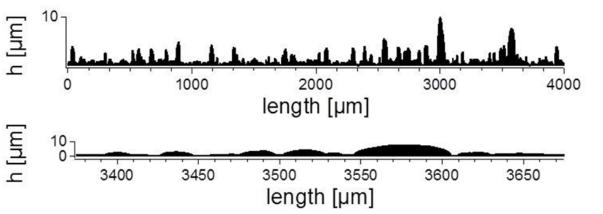


Fig. 8. Modelled surface profile for the as deposited sample. a. – entire model surface, the vertical dimension is 40 times magnified; b. - a specific region drawn in natural aspect ratio

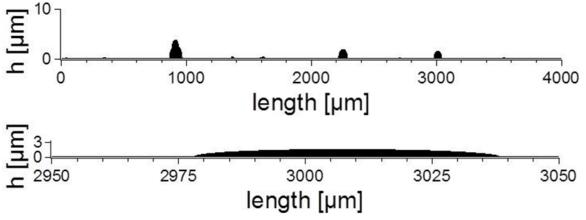
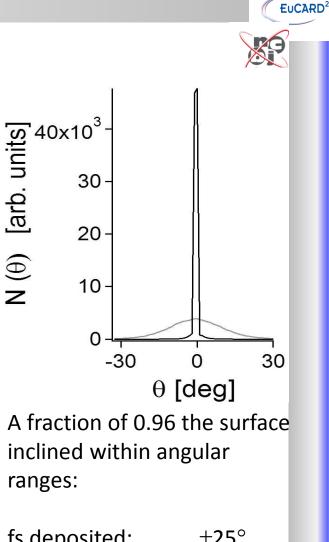


Fig. 9. Modelled surface profile for the flattened sample. a. – entire model surface, the vertical dimension is 40 times magnified; b. - a specific region drawn in natural aspect ratio



fs deposited:	±25°
flattened:	±5°

Electric field improvement

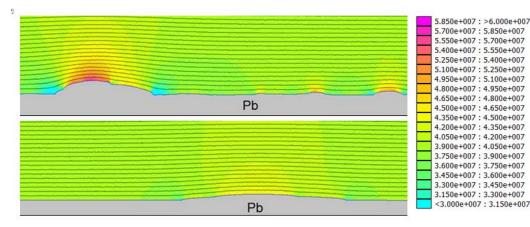


Fig. 11. Maps of electric field in the vicinity of modelled surface. a. – as deposited sample; b. – flattened sample

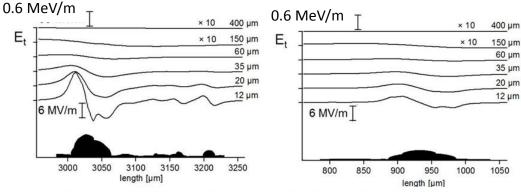
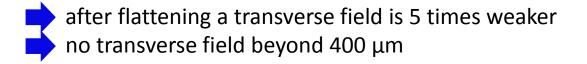
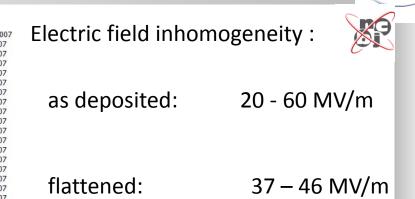


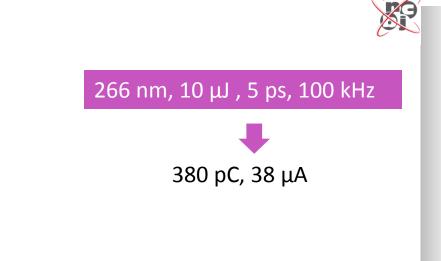
Fig. 12. Transverse contribution of the electric field calculated for the model surface for the regions containing the highest protrusions. a. – as deposited sample; b. – flattened sample





EUCARD²

E _{cathode}	40 MV/m
QE at 266 nm	1.8.10-4
Bunch rep. rate	100-250 kHz
Bunch charge	250-100 pC
P of irradiating laser at 266nm	1 W
Normalized emittance for 250pC	<0.5 µm rad



EUCARD²

Long term stability is being tested at HZDR

Dark current modelling base on breakdown current measurements with pulsed E field
Beam dynamics calculation – emittance evaluation

R&D at DESY

The 1.5-cell gun cavity prototype was built at TJNAF. The present plug version has very effective cooling of the cathode.





New plug with LHe channels

1.5-cell , 1.3 GHz gun cavity

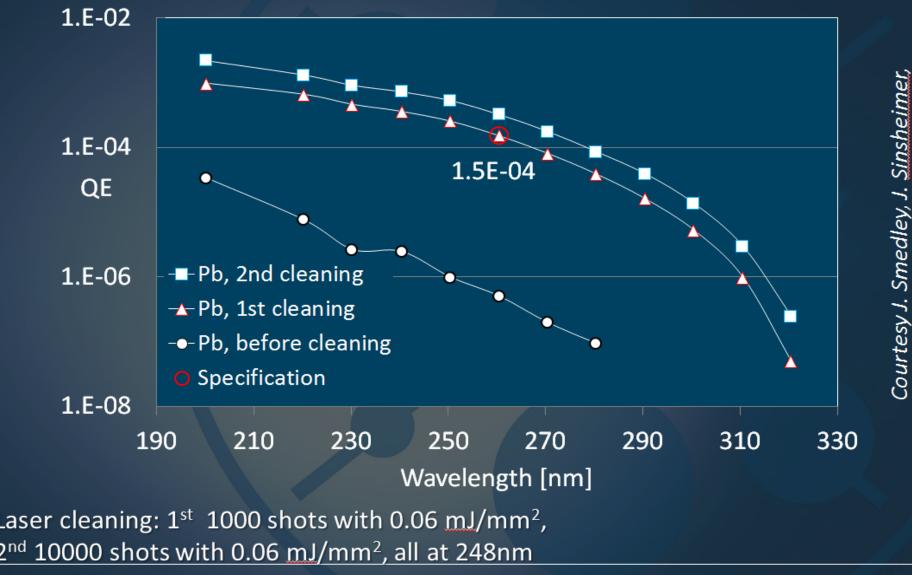


Nb/Pb cathode

J. Sekutowicz, SRF-gun at DESY, EuCard2, April 4-5, 2016

R&D at DESY

Recent QE test at BNL of the Pb coating on new plug

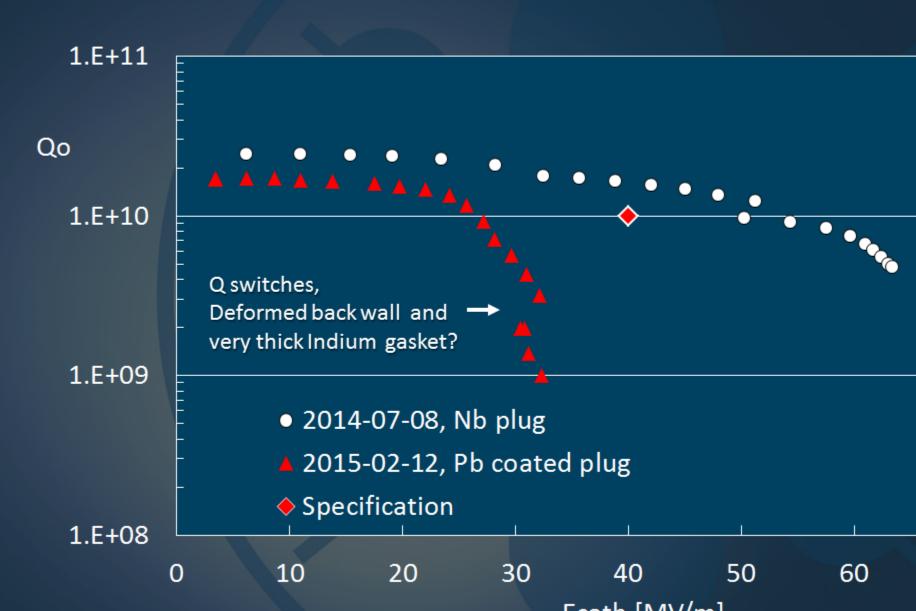


J. Sekutowicz, SRF-gun at DESY, EuCard2, April 4-5, 2016

M. Gaowei and V. Gofron

R&D at DESY

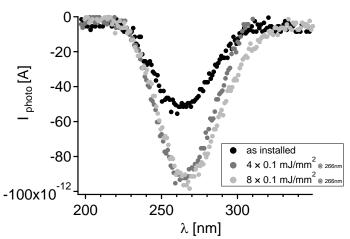
The test results of 1.5-cell gun cavity with Nb and Pb-coated catho



Instruments development







Pb/Nb Sample ex-situ prepared with 200 pulses of 0.5 mJ/mm² at 532 nm then treated with 8×0.1 mJ/mm² at 266 with . QE= 6^{-10⁻⁴} ± 5^{-10⁻⁴} (preliminary results)

Built since 2014:

150 W Xe lamp + monochromator +fiber optical path+ picoamperometer 255 nm 1 W diodes Nd YAG +IV harmonics generator 30 μ J, 10 ns, 20 Hz + collimation Pulser 12.5 kV + 50 μ m precise manipulators: 1. sample holder, 2. Farady cup



MS 80 Demonstrated operation of improved deposition system, Pb layers of 1 μ m in thickness

Direct arc deposition

D12.8 Optimised procedure for microdorplets flattening with an UV laser

Pulsed plasma flattening





Thanks for the attention

Thanks for the collaboration on photocathodes and innovative RF technologies